NSN 5961-01-532-7865

Diode Semiconductor Device - Page 1 of 1



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Overall Length:
Between 0.200 inches and 0.225 inches
Overall Diameter:
Between 0.137 inches and 0.148 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
13.6 breakdown voltage, dc and 12.0 working peak reverse voltage
Current Rating Per Characteristic:
80.00 amperes forward current, average preset
Power Rating Per Characteristic:
2.5 watts small-signal input power, common-collector major
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Terminal Type And Quantity:
2 bonding pad
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:

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